

AMENDMENTS TO THE TITLE AND ABSTRACT

In The Title:

Please amend the Title as follows:

SEMICONDUCTOR STORAGE DEVICE MANUFACTURING METHOD
WHICH FORMS A HYDROGEN DIFFUSION INHIBITING LAYER

In the Abstract:

Please replace the Abstract with the new Abstract attached hereto as
Appendix A.

AMENDMENTS TO THE DRAWINGS:

The attached sheet of drawing includes changes to Fig. 21. This sheet, which includes Fig. 21, replaces the original sheet including Fig. 21. In Fig. 21, the previously omitted numeral 10 has been provided, corresponding to the use of the numeral 10 in the specification.